## 3A / 12V Bipolar transistor

## 2SD2678

## - Applications

Low frequency amplification, driver

## -Features

1) Collector current is high.
2) Low collector-emitter saturation voltage.
$\left(\mathrm{VCE}_{\mathrm{C}}\right.$ (sat) $\leq 250 \mathrm{mV}$ at $\mathrm{Ic}=1.5 \mathrm{~A}$, IB $\left.=30 \mathrm{~mA}\right)$

## -Structure

NPN epitaxial planar silicon transistor

- Absolute maximum ratings $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

| Parameter |  | Symbol | Limits | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Collector-base voltage |  | Vсво | 15 | V |
| Collector-emitter voltage |  | Vceo | 12 | V |
| Emitter-base voltage |  | Vebo | 6 | V |
| Collector current | DC | lc | 3 | A |
|  | Pulse | Іс> | $6 * 1$ |  |
| Power dissipation |  | Pc | $0.5 * 2$ | W |
|  |  | $2 * 3$ |  |
| Junction temperature |  |  | Tj | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature |  | Tstg | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

*2 Each terminal mounted on a recommended land.
$* 3$ Mounted on a $40 \times 40 \times 0.7 \mathrm{~mm}$ ceramic board.

## -External dimensions (Unit : mm)

| MPT3 |  |
| :---: | :---: |
|  |  |
| (1)Base | 3.0 |
| (2)Collector |  |
| (3)Emitter | Abbreviated symbol : XX |

## -Packaging specifications

|  | Package | MPT3 |
| :--- | :--- | :---: |
|  | Packaging type | Taping |
|  | Code | T100 |
| Part No. | Basic ordering unit (pieces) | 1000 |
| 2SD2678 |  | $\bigcirc$ |

-Electrical characteristics (Ta=25 ${ }^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Collector-emitter breakdown voltage | BVceo | 12 | - | - | V | $\mathrm{Ic}=1 \mathrm{~mA}$ |
| Collector-base breakdown voltage | BVcbo | 15 | - | - |  | $\mathrm{lc}=10 \mu \mathrm{~A}$ |
| Emitter-base breakdown voltage | BVebo | 6 | - | - |  | $\mathrm{I}_{\mathrm{E}}=10 \mu \mathrm{~A}$ |
| Collector cut-off current | Icbo | - | - | 100 | nA | V cb $=15 \mathrm{~V}$ |
| Emitter cut-off current | lebo | - | - | 100 |  | $\mathrm{V}_{\text {EB }}=6 \mathrm{~V}$ |
| Collector-emitter saturation voltage | VCE(sat) | - | 120 | 250 | mV | $\mathrm{Ic} / \mathrm{lb}=1.5 \mathrm{~A} / 30 \mathrm{~mA}$ |
| DC current gain | hfe * | 270 | - | 680 | - | VCE=2V, $\mathrm{Ic}=500 \mathrm{~mA}$ |
| Transition frequency | ft * | - | 360 | - | MHz | VCE= $2 \mathrm{~V}, \mathrm{IE}=-500 \mathrm{~mA}, \mathrm{f}=100 \mathrm{MHz}$ |
| Collector output capacitance | Cob | - | 20 | - | pF | $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{~V}, \mathrm{le}=0 \mathrm{~mA}, \mathrm{f}=1 \mathrm{MHz}$ |

## -Electrical characteristics curves



Fig. 1 DC current gain vs. collector current


Fig. 4 Grounded emitter propagation characteristics


Fig. 2 Collector-emitter saturation voltage vs. collector current


Fig. 5 Gain bandwidth product vs. emitter current


Fig. 3 Base-emitter saturation voltage vs.collector current


Fig. 6 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

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